HD74AC174

Hex D-Type Flip-Flop with Master Reset

HITACHI

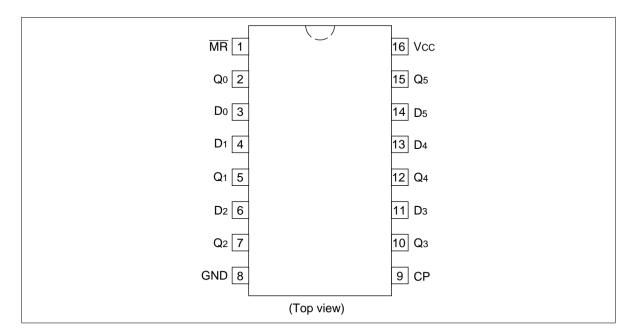
Description

The HD74AC174 is a high-speed hex D flip-flop. The device is used primarily as a 6-bit edge-triggered storage register. The information on the D inputs is transferred to storage during the Low-to-High clock transition. The device has a Master Reset to simultaneously clear all flip-flops.

Feature

• Outputs Source/Sink 24 mA

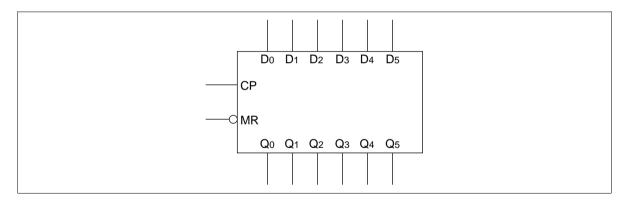
Pin Arrangement





HD74AC174

Logic Symbol



Pin Names

D₀ to D₅ Data Inputs

 Q_0 to Q_5 Outputs

Functional Description

The HD74AC174 consists of six edge-triggered D flip-flops with individual D inputs and Q outputs. The Clock (CP) and Master Reset (\overline{MR}) are common to all flip-flops. Each D input's state is transferred to the corresponding flip-flops's output following the Low-to-High Clock (CP) transition. A Low input to the Master Reset (\overline{MR}) will force all outputs Low independent of Clock or Data inputs. The HD74AC174 is useful for applications where the true output only is required and the Clock and Master Reset are common to all storage elements.

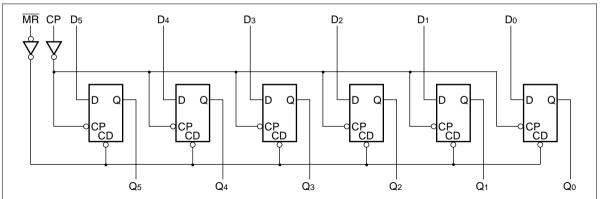
Truth Table

Inputs			Output		
MR	СР	D	Q		
L	Х	Х	L		
Н		Н	Н		
Н	\int	L	L		
Н	L	Х	Q		

H: High Voltage LevelL: Low Voltage Level

X: Immaterial

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

DC Characteristics (unless otherwise specified)

Item	Symbol	Max	Unit	Condition
Maximum quiescent supply current	I _{cc}	80	μΑ	$V_{IN} = V_{CC}$ or ground, $V_{CC} = 5.5 \text{ V}$, Ta = Worst case
Maximum quiescent supply current	I _{cc}	8.0	μΑ	$V_{IN} = V_{CC}$ or ground, $V_{CC} = 5.5 \text{ V}$, Ta = 25°C

AC Characteristics: HD74AC174

-			Ta = +25°C C _L = 50 pF		Ta = -40° C to $+85^{\circ}$ C C _L = 50 pF			
Item	Symbol	V _{cc} (V)*1	Min	Тур	Max	Min	Max	Unit
Maximum clock	f _{max}	3.3	90	100	_	70	_	MHz
frequency		5.0	100	125	_	100	_	
Propagation delay	t _{PLH}	3.3	1.0	9.0	11.5	1.0	12.5	ns
CP to Q _n		5.0	1.0	6.0	8.5	1.0	9.5	
Propagation delay	t _{PHL}	3.3	1.0	8.5	11.0	1.0	12.0	ns
CP to Q _n		5.0	1.0	6.0	8.0	1.0	9.0	
Propagation delay	t _{PHL}	3.3	1.0	9.0	11.5	1.0	12.5	ns
$\overline{\text{MR}}$ to Q_n		5.0	1.0	7.0	9.0	1.0	10.5	

Note: 1. Voltage Range 3.3 is $3.3 \text{ V} \pm 0.3 \text{ V}$ Voltage Range 5.0 is $5.0 \text{ V} \pm 0.5 \text{ V}$

HD74AC174

AC Operating Requirements: HD74AC174

			Ta = +25°C C _L = 50 pF		Ta = -40°C to +85°C C _L = 50 pF	
Item	Symbol	V _{cc} (V)*1	Тур	Guaranteed	Minimum	Unit
Setup time, HIGH or LOW	t _{su}	3.3	2.5	6.5	7.0	ns
D _n to CP		5.0	2.0	5.0	5.5	
Hold time, HIGH or LOW	t _h	3.3	1.0	3.0	3.0	ns
D _n to CP		5.0	0.5	3.0	3.0	_
MR pulse width, LOW	t _w	3.3	1.0	5.5	7.0	ns
		5.0	1.0	5.0	5.0	_
CP pulse width	t _w	3.3	1.0	5.5	7.0	ns
		5.0	1.0	5.0	5.0	_
Recovery time	t _{rec}	3.3	0	2.5	2.5	ns
MR to CP		5.0	0	2.0	2.0	_

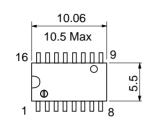
Note: 1. Voltage Range 3.3 is $3.3 \text{ V} \pm 0.3 \text{ V}$ Voltage Range 5.0 is $5.0 \text{ V} \pm 0.5 \text{ V}$

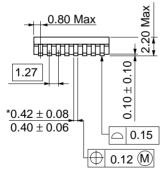
Capacitance

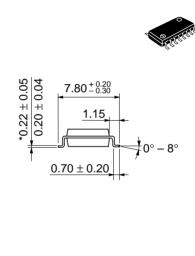
Item	Symbol	Тур	Unit	Condition
Input capacitance	C _{IN}	4.5	pF	V _{CC} = 5.5 V
Power dissipation capacitance	$C_{\scriptscriptstyle{PD}}$	85.0	pF	V _{CC} = 5.0 V

Unit: mm 19.20 20.00 Max 16 7.40 Max 6.30 1.3 1.11 Max 7.62 5.06 Max 2.54 Min 0.51 Min $0.25^{+0.13}_{-0.05}$ 0.48 ± 0.10 2.54 ± 0.25 $0^{\circ} - 15^{\circ}$ Hitachi Code DP-16 **JEDEC** Conforms EIAJ Conforms Weight (reference value) 1.07 g

Unit: mm







*Dimension including the plating thickness
Base material dimension

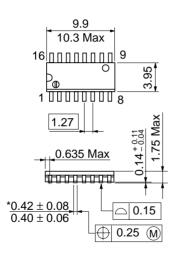
EIAJ Conforms
Weight (reference value) 0.24 g

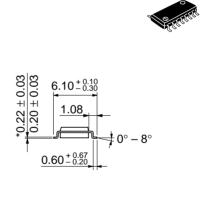
FP-16DA

Hitachi Code

JEDEC

Unit: mm

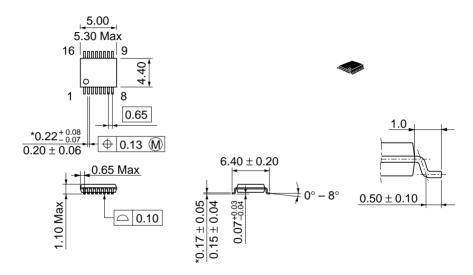




*Dimension including the plating thickness
Base material dimension

Hitachi Code	FP-16DN
JEDEC	Conforms
EIAJ	Conforms
Weight (reference value)	0.15 g

Unit: mm



	Hitachi Code	TTP-16DA
	JEDEC	_
*Dimension including the plating thickness	EIAJ	
Base material dimension	Weight (reference value)	0.05 g

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